

Features

- 44-V Supply Max Rating
- $\pm 15\text{-V}$ Anlog Signal Range
- On-Resistance- $r_{DS(ON)}$: 25Ω
- Fast Switching- t_{ON} : 110ns
- Ultra Low Power-PD: $0.35\mu\text{W}$
- TTL,CMOS Compatible
- Single Supply Capability

Benefits

- Widest Dynamic Range
- Low Signal Errors and Distortion
- Break-Before-Make Switching Action
- Simple Interfacing

Applications

- Precision Automatic Test Equipment
- Precision Data Acquisition
- Communication Systems
- Battery Powered Systems
- Computer Peripherals

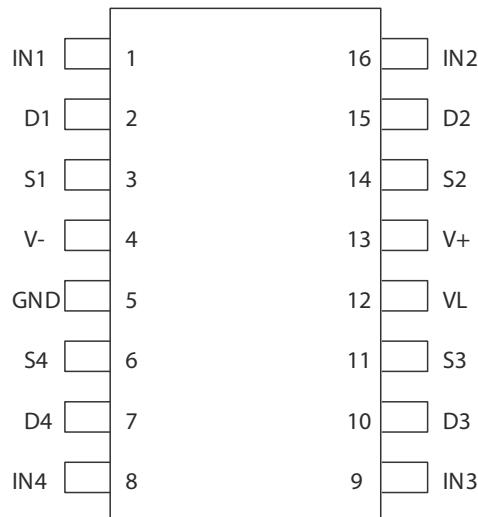
Description

The V411 series of monolithic quad analog switches was designed to provide high speed, low error switching of precision analog signals.

Widely used in precision data acquisition and communication systems. Combining low power with high speed. Encapsulation with SOP16.

1. Functional Block Diagram And Pin Configuration

V411



TRUTH TABLE

| Logic | V411 |
|-------|------|
| 0 | ON |
| 1 | OFF |

Logic "0" $\leq 0.8\text{ V}$

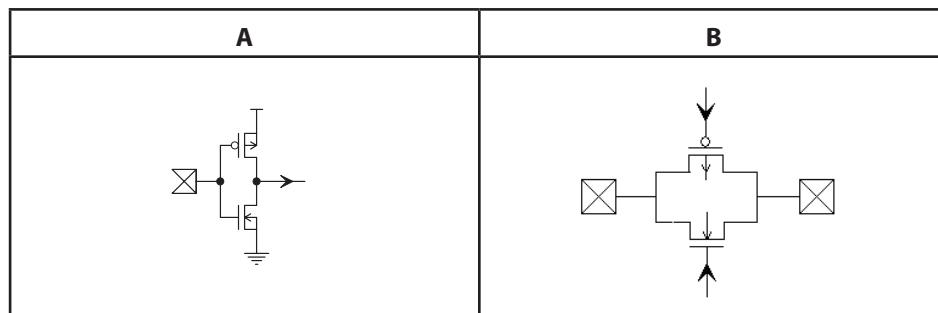
Logic "1" $\geq 2.4\text{ V}$

Four CMOS analog switches included Capability of voltage control circuit

| Symbol | Test Conditions | Status |
|--------|-----------------|------------|
| IN1 | 0 | S1& D1 on |
| | 1 | S1& D1 off |
| IN2 | 0 | S1& D1 on |
| | 1 | S1& D1 off |
| IN3 | 0 | S1& D1 on |
| | 1 | S1& D1 off |
| IN4 | 0 | S1& D1 on |
| | 1 | S1& D1 off |

2. Pin Description and Structure Scheme

| PIN | Symbol | Function | Attribute | Structure Scheme |
|-----|--------|---|-----------|------------------|
| 1 | IN1 | Logic control port of the first switch | I | A |
| 2 | D1 | Output of D of the first switch | I/O | B |
| 3 | S1 | Output of S of the first switch | I/O | B |
| 4 | V- | Negative power supply | | |
| 5 | GND | GND | | |
| 6 | S4 | Output of S of the forth switch | I/O | B |
| 7 | D4 | Output of D of the forth switch | I/O | B |
| 8 | IN4 | Logic control port of the forth switch | I | A |
| 9 | IN3 | Logic control port of the third switch | I | A |
| 10 | D3 | Output of D of the third switch | I/O | B |
| 11 | S3 | Output of S of the third switch | I/O | B |
| 12 | VL | Digital power supply | | |
| 13 | V+ | Positive power supply | | |
| 14 | S2 | Output of S of the second switch | I/O | B |
| 15 | D2 | Output of D of the second switch | I/O | B |
| 16 | IN2 | Logic control port of the second switch | I | A |



Absolute Maximum Ratings

Supply Voltage (VDD).....-20~20V
 Input Voltage (VIN).....0~6V
 Output Voltage (VOUT).....-20~20V

Benefits

Operating Temperature (Tamb).....-40~85 °C
 Storage Temperature (Tstg).....-65~150 °C
 Note: Unless otherwise specified, Tamb=25 °C

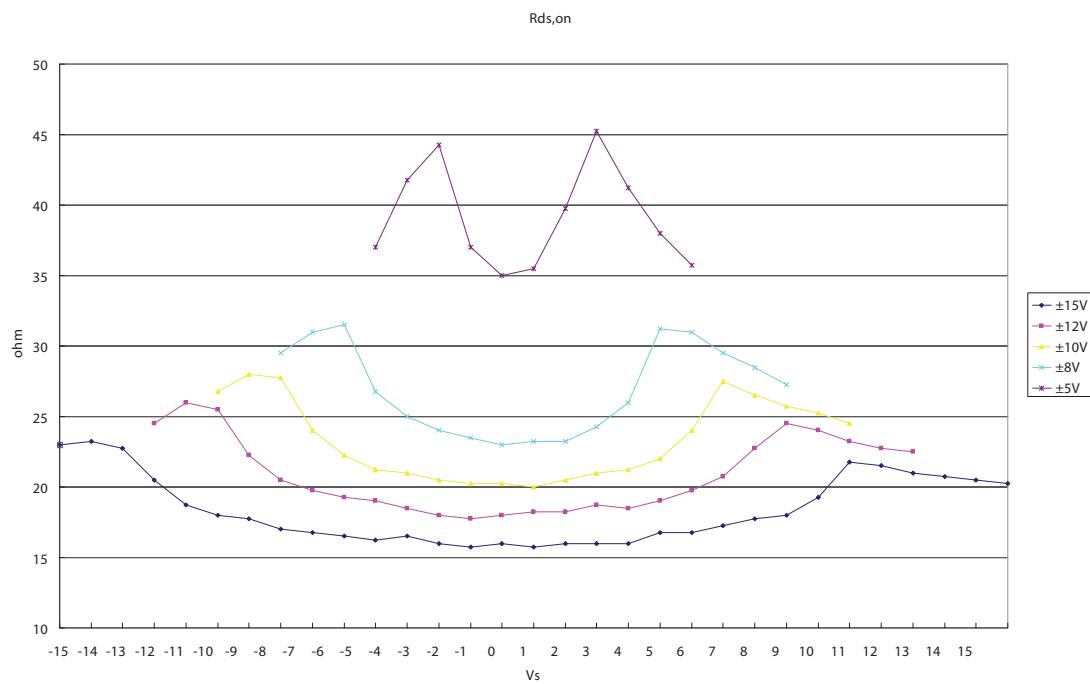
Electrical Characteristics

| Parameter | Symbol | Test Conditions | Value | | | Unit |
|--------------------------------|---------------------|--|-------|-------|-----|------|
| | | | Min | Typ | Max | |
| Analog Switch | | | | | | |
| Analog signal range | V _{analog} | V ₊ =15 V, V ₋ =-15 V | -15 | | 15 | V |
| Logical input -High voltage | V _{inH} | V _L =5 V | 2.8 | | 5 | V |
| Logical input -low voltage | V _{inL} | V _L =5 V | 0 | | 0.6 | V |
| Switch On Resistance 1 | R _{dson1} | V ₊ =13.5 V, V ₋ =-13.5 V I _S =-10 mA, V _d =8.5 V | 15 | 25 | 35 | Ω |
| Switch Off Resistance 2 | R _{dson2} | V ₊ =12 V, V ₋ =0 V I _S =-10 mA, V _d =3.8 V | 18 | 40 | 80 | Ω |
| Dynamic Characteristics | | | | | | |
| Turn-on Time1 | T _{on1} | V ₊ =15 V, V ₋ =-15 V, R _L =300 Ω C _L =35 pf, V _s =±10 V | | 110 | 175 | ns |
| Turn-off Time1 | T _{off1} | | | 100 | 145 | ns |
| Turn-on Time2 | T _{on2} | V ₊ =12 V, V ₋ =0 V, R _L =300 Ω C _L =35 pf, V _s =8 V | | 175 | 250 | ns |
| Turn-off Time2 | T _{off2} | | | 95 | 125 | ns |
| Power Supplies | | | | | | |
| Positive Supply Current | I ₊ | V ₊ =16.5 V, V ₋ =-16.5 V V _{IN} =0 V or 5 V | | 0.001 | 1 | μA |
| Negative Supply Current | I ₋ | | | 0.001 | 1 | μA |

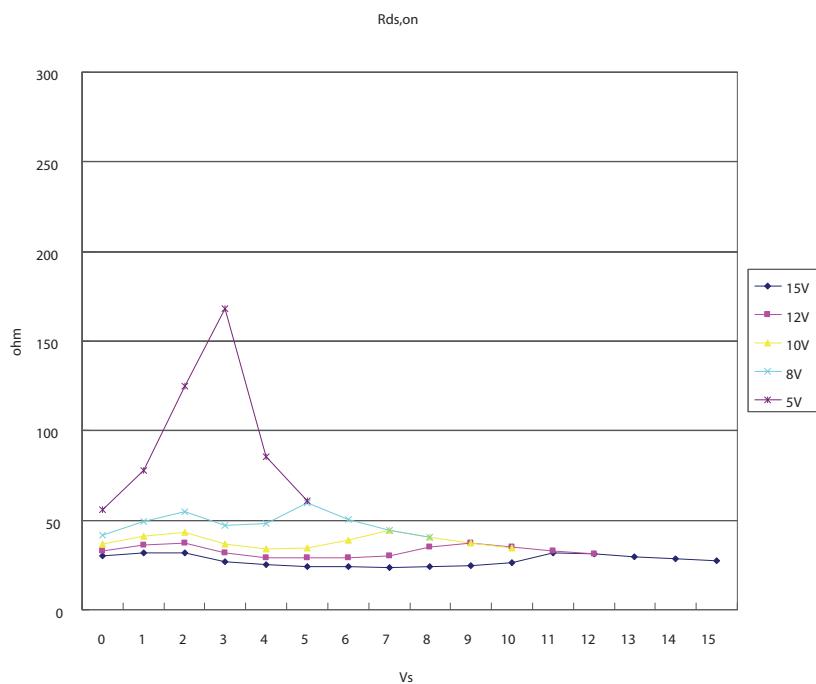
Note: Unless otherwise specified, T_{amb}= 25 °C, V_L=5 V, V_{IN}=2.8 V, 0.6 V

3. Typical Characteristics (25°C Unless Noted)

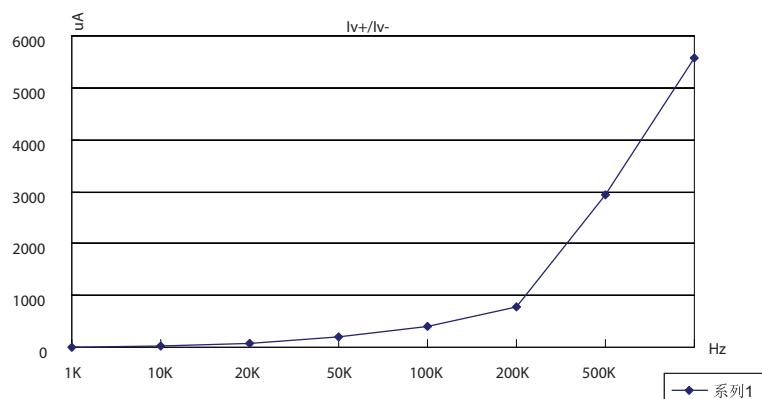
- $R_{DS,ON}$ TYPICAL CHARACTERISTICS (ROOM TEMPERATURE)



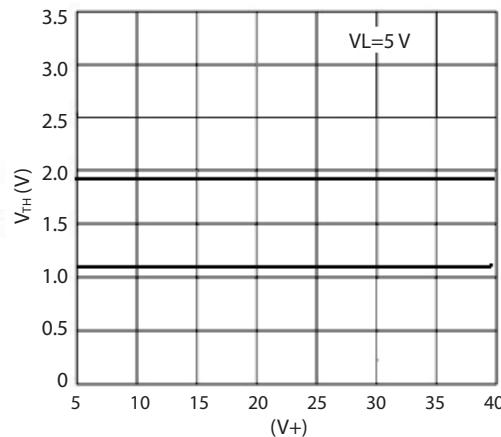
- $R_{DS,ON}$ TYPICAL CHARACTERISTICS WITH UNIPOLAR SUPPLY (ROOM TEMPERATURE)



- **Switching Time vs Input Switching Frequency**

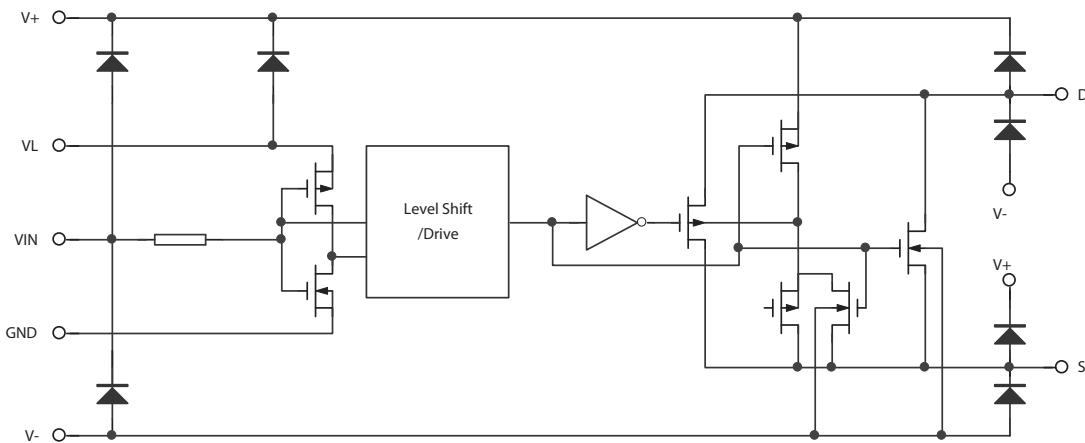


- **Input Switching Threshold vs Supply Voltage**

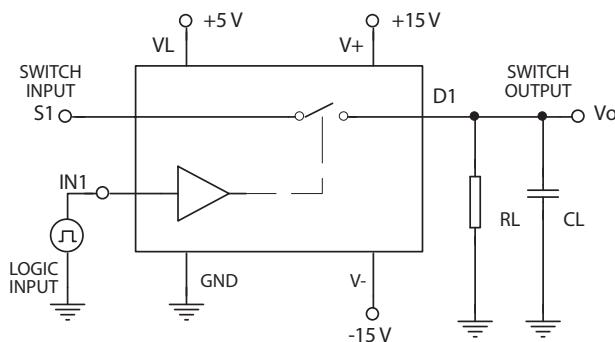


Input Switching Threshold vs Supply Voltage

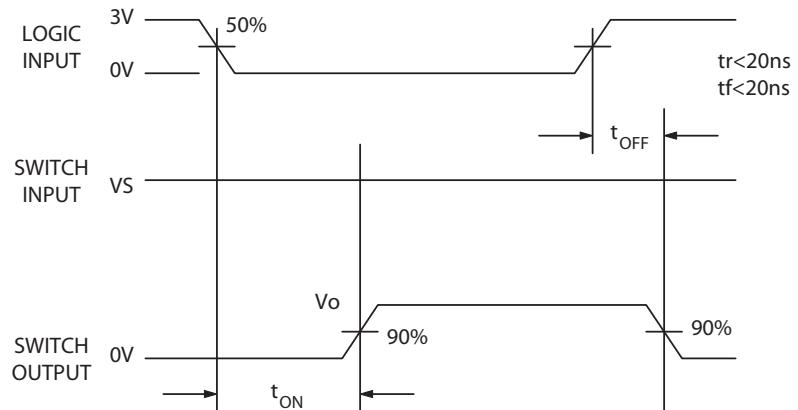
4. Schematic Diagram (Typical Channel)



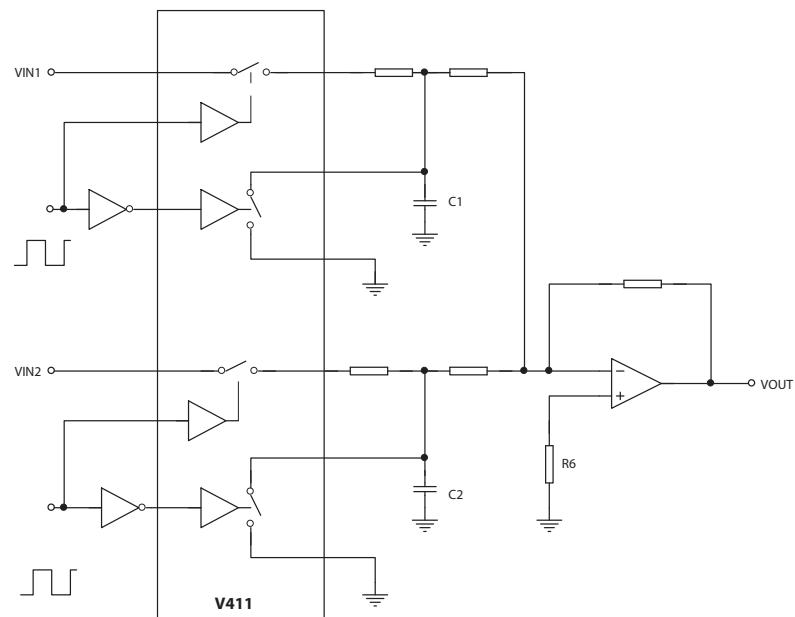
5. Test Circuits



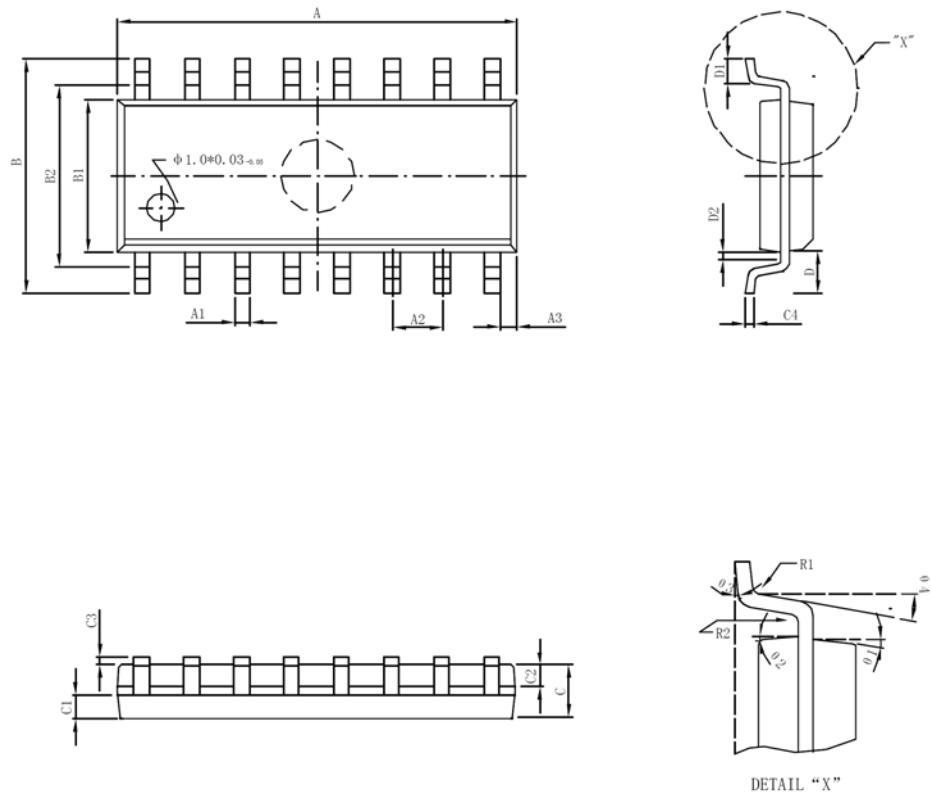
$$V_o = V_s \frac{R_L}{L + r_{DS(ON)} R}$$



Applications



Package Dimensions



| Symbol | Min(mm) | Max(mm) | Symbol | Min(mm) | Max(mm) |
|--------|---------|---------|--------|---------|----------|
| A | 9.9 | 10.10 | C4 | | 0.2 TYP |
| A1 | 0.356 | 0.456 | D | | 1.05 TYP |
| A2 | | 1.27TYP | D1 | 0.40 | 0.70 |
| A3 | | 0.35TYP | D2 | 0.22 | 0.42 |
| B | 5.84 | 6.24 | R1 | | 0.15 TYP |
| B1 | 3.84 | 4.04 | R2 | | 0.15 TYP |
| B2 | | 5.0TYP | θ1 | | 8 °TYP |
| C | 1.35 | 1.55 | θ2 | | 8 °TYP |
| C1 | 0.61 | 0.71 | θ3 | | 4 °TYP |
| C2 | 0.54 | 0.64 | θ4 | | 15 °TYP |
| C3* | 0.10 | 0.30 | | | |